

Features

- Surface Mount
- No Wirebonds Required
- Rugged Silicon-Glass Construction
- Silicon Nitride Passivation
- Polymer Scratch Protection
- Low Parasitic Capacitance and Inductance
- High Average and Peak Power Handling
- RoHS Compliant

Description

This device is a silicon, glass PIN diode surmount chip fabricated with M/A-COM Tech's patented HMIC™ process. This device features two silicon pedestals embedded in a low loss, low dispersion glass. The diode is formed on the top of one pedestal and connections to the backside of the device are facilitated by making the pedestal sidewalls electrically conductive. Selective backside metallization is applied producing a surface mount device. This vertical topology provides for exceptional heat transfer. The topside is fully encapsulated with silicon nitride and has an additional polymer layer for scratch and impact protection. These protective coatings prevent damage to the junction and the anode air-bridge during handling and assembly.

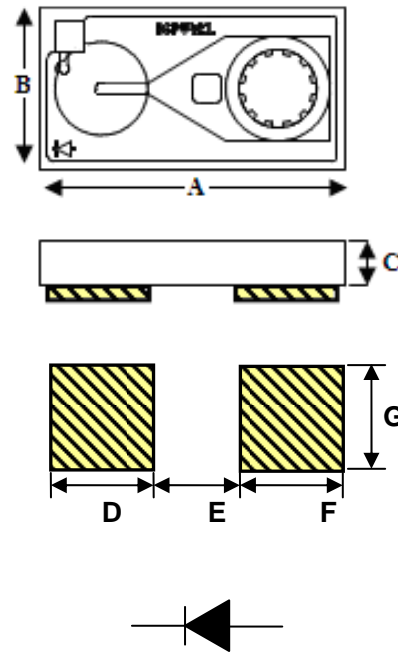
Applications

These packageless devices are suitable for moderate incident power applications, $\leq 10W/C.W.$ or where the peak power is $\leq 50W$, pulse width is $\leq 1\mu S$, and duty cycle is $\leq 0.01\%$. Their low parasitic inductance, 0.4 nH, and excellent RC constant, make these devices a superior choice for higher frequency switch elements when compared to their plastic package counterparts.

Absolute Maximum Ratings¹ @ $T_{AMB} = +25^{\circ}C$ (unless otherwise specified)

Parameter	Absolute Maximum				
	MADP-042...-13060	305	405	505	905
C.W. Incident Power dBm	40	44	43	35	
Forward Current	250 mA				
Reverse Voltage	-80 V				
Operating Temperature	-55°C to +125°C				
Storage Temperature	-55°C to +150°C				
Junction Temperature	+175°C				
Mounting Temperature	+280°C for 10 seconds				

1. Exceeding these limits may cause permanent damage.



DIM	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.040	0.042	1.025	1.075
B	0.021	0.023	0.525	0.575
C	0.004	0.008	0.102	0.203
D	0.013	0.015	0.325	0.375
E	0.011	0.013	0.275	0.325
F	0.013	0.015	0.325	0.375
G	0.019	0.021	0.475	0.525

Notes:

1. Backside metal: 0.1 μM thick.
2. Yellow hatched areas indicate backside ohmic gold contacts.
3. All devices have the same outline dimensions (A to G).

MADP-042XX5-13060 Series



SURMOUNT™ PIN Diodes:
RoHS

Rev. V6

Electrical Specifications @ $T_{AMB} = +25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Conditions	Units	Min	Typ	Max	Min	Typ	Max
				MADP-042305-13060			MADP-042505-13060		
Capacitance	$C_T^{1,3}$	- 10V, 1 MHz 1	pF		0.14	0.22		0.28	0.40
Capacitance	$C_T^{1,3}$	- 10 V, 1 GHz 1,3	pF		0.15			0.28	
Capacitance	$C_T^{1,3}$	- 40 V, 1 MHz 1	pF		0.13	0.22		0.27	0.40
Capacitance	$C_T^{1,3}$	- 40 V, 1 GHz 1,3	pF		0.14			0.27	
Resistance	$R_S^{2,3}$	+ 20 mA, 1 GHz 2,3	W		1.32			0.83	
Resistance	$R_S^{2,3}$	+ 50 mA, 1 GHz 2,3	W		1.18			0.76	
Forward Voltage	V_F	+ 10 mA	V		0.87	1.00		0.84	1.00
Reverse Leakage Current	I_R	-80V	uA			10			10
Input Third Order Intercept Point	IIP ³	F 1= 1000 MHz F2 = 1010 MHz Input Power = +20 dBm I bias = + 20 mA	dBm		72			76	
C.W. Thermal Resistance	θ		$^{\circ}\text{C/W}$		145			115	
Lifetime	T_L	+10 mA / -6 mA (50% - 90% V)	nS		180			210	

Parameter	Symbol	Conditions	Units	Min	Typ	Max	Min	Typ	Max
				MADP-042405-13060			MADP-042905-13060		
Capacitance	$C_T^{1,3}$	- 10 V, 1 MHz 1	pF		0.61	0.75		0.06	0.18
Capacitance	$C_T^{1,3}$	- 10 V, 1 GHz 1,3	pF		0.61			0.06	
Capacitance	$C_T^{1,3}$	- 40 V, 1 MHz 1	pF		0.57	0.75		0.06	0.18
Capacitance	$C_T^{1,3}$	- 40 V, 1 GHz 1,3	pF		0.58			0.06	
Resistance	$R_S^{2,3}$	+ 20 mA, 1 GHz 2,3	W		0.62			3.14	
Resistance	$R_S^{2,3}$	+ 50 mA, 1 GHz 2,3	W		0.58			2.60	
Forward Voltage	V_F	+ 10 mA	V		0.82	1.00		0.93	1.00
Reverse Leakage Current	I_R	-80V	uA			10			10
Input Third Order Intercept Point	IIP ³	F 1= 1000 MHz F2 = 1010 MHz Input Power = +20 dBm I bias = + 20 mA	dBm		80			65	
C.W. Thermal Resistance	θ^4		$^{\circ}\text{C/W}$		100			185	
Lifetime	T_L	+10 mA / -6 mA (50% - 90% V)	nS		255			140	

1. Total capacitance, C_T , is equivalent to the sum of junction capacitance, C_J , and parasitic capacitance, C_{par} .
2. Series resistance R_S is equivalent to the total diode resistance : $R_S = R_J$ (Junction Resistance) + R_C (Ohmic Resistance)
3. R_S and C_T are measured on an HP4291A Impedance Analyzer with die mounted in an ODS-1134 package.
4. Theta (θ) is measured with the die mounted in an ODS-1134 package.

Specifications Subject to Change Without Notice.

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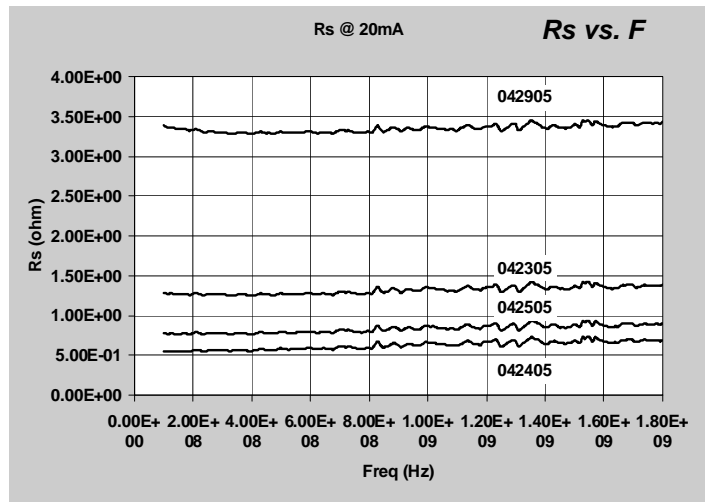
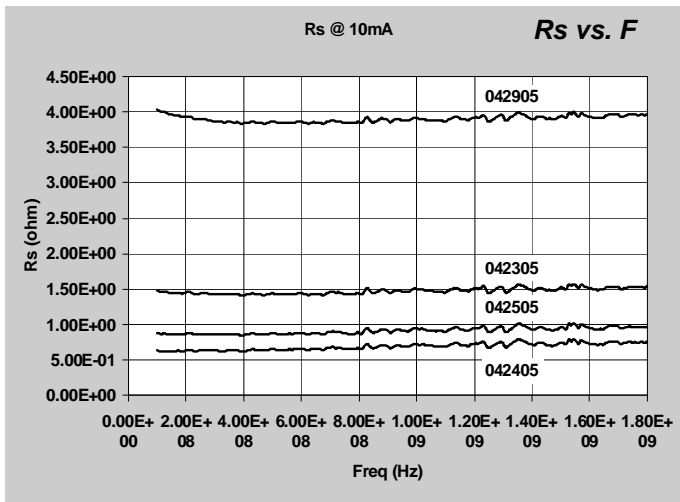
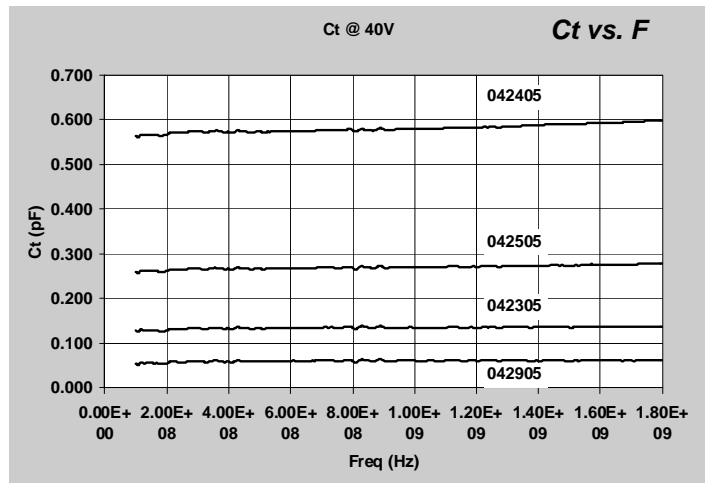
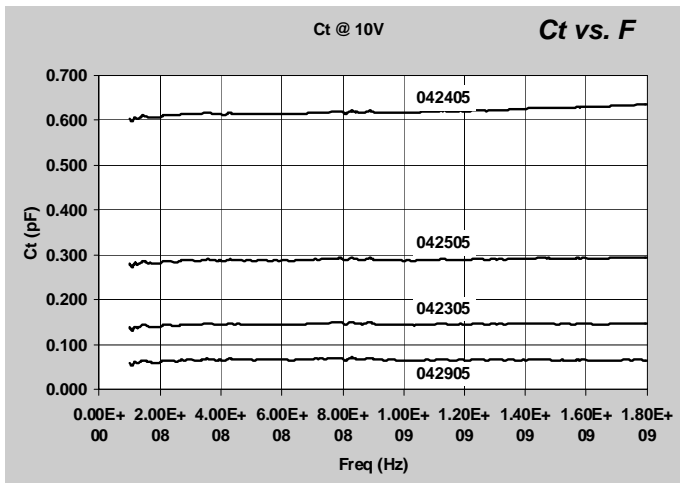
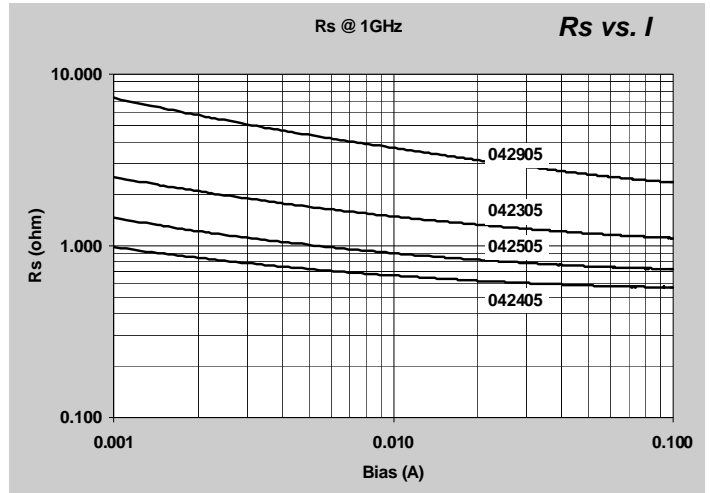
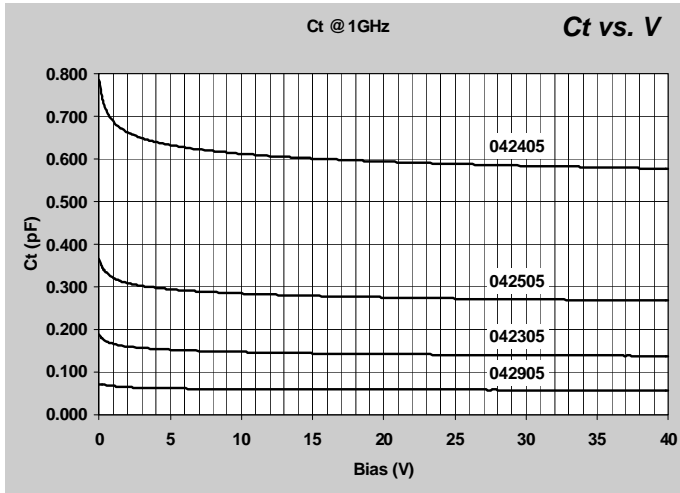
MADP-042XX5-13060 Series



SURMOUNT™ PIN Diodes:
RoHS

Rev. V6

Typical Performance @ $T_{AMB} = +25\text{ }^{\circ}\text{C}$



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Handling Procedures

All semiconductor chips should be handled with care to avoid damage or contamination from perspiration and skin oils. The use of plastic tipped tweezers or vacuum pickups is strongly recommended for individual components. Bulk handling should insure that abrasion and mechanical shock are minimized.

Bonding Techniques

Attachment to a circuit board is made simple through the use of surface mount technology. Mounting pads are conveniently located on the bottom surface of these devices and are removed from the active junction locations. These devices are well suited for solder attachment onto hard and soft substrates. The use of 80Au/20Sn, or RoHS compliant solders is recommended. For applications where the average power is ~1W, conductive silver epoxy may also be used. Cure per manufacturers recommended time and temperature. Typically 1 hour at 150°C.

When soldering these devices to a hard substrate, hot gas die bonding is preferred. A vacuum tip pick-up tool and a force of 60 to 100 grams applied to the top surface of the device is recommended. When soldering to soft substrates, such as Duroid, it is recommended to use a soft solder at the circuit board to mounting pad interface. Position the die so that its mounting pads are aligned with the circuit board mounting pads. While applying a downward force perpendicular to the top surface of the die, apply heat near the circuit trace and diode mounting pad. The solder connection to the two pads should not be made one at a time as this will create unequal heat flow and thermal stress to the part. Solder reflow should not be performed by causing heat to flow through the top surface of the die to the back. Since the HMIC glass is transparent, the edges of the mounting pads can be visually inspected through the die after attachment is completed.

Typical re-flow profiles for Sn60/Pb40 and RoHS compliant solders is provided in [Application Note M538](#), "Surface Mounting Instructions" and can viewed on the MA-COM website @ www.macomtech.com

Ordering Information

The MADP-042XX5-13060 series of surmounts may be ordered in either gel packs or tape and reeled by adding the appropriate suffix per the table below. Tape and reel dimensions are provided in [Application Note M513](#) located on the M/A-COM Tech's website @ www.macomtech.com.

Part Number		
Gel Pack	Tape and Reel	Tape and Reel
	Surf Tape	Pocket Tape
MADP-042305-13060G	MADP-042305-13060T	MADP-042305-13060P
MADP-042405-13060G	MADP-042405-13060T	MADP-042405-13060P
MADP-042505-13060G	MADP-042505-13060T	MADP-042505-13060P
MADP-042905-13060G	MADP-042905-13060T	MADP-042905-13060P